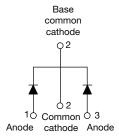


Vishay Semiconductors

Schottky Rectifier, 2 x 15 A



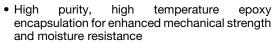


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PRODUCT SUMMARY					
Package	TO-262AA				
I _{F(AV)}	2 x 15 A				
V_{R}	30 V				
V _F at I _F	0.37 V				
I _{RM}	350 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Common cathode				
E _{AS}	15 mJ				

FEATURES

- 150 °C T_J operation
- Center tap configuration
- Very low forward voltage drop
- High frequency operation





COMPLIANT HALOGEN FREE

- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Halogen-free according to IEC 61249-2-21 definition
- Compliant to RoHS directive 2002/95/EC
- AEC-Q101 qualified

DESCRIPTION

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	30	A		
V _{RRM}		30	V		
V _F	15 Apk, T _J = 125 °C (per leg)	0.37	V		
TJ	Range	- 55 to 150	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-30L30CT-1PbF	UNITS		
Maximum DC reverse voltage	V _R	30	V		
Maximum working peak reverse voltage	V _{RWM}	30	V		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average per device		50 % duty cycle at T _C = 140 °C, rectangular waveform		30	
forward current per leg	I _{F(AV)}			15	
Maximum peak one cycle non-repetitive	l=a	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	1450	Α
surge current	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	220	
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 7.5 mH		15	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		2	Α

VS-30L30CT-1PbF

Vishay Semiconductors

Schottky Rectifier, 2 x 15 A



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Revision: 05-Oct-10

ELECTRICAL SPECIFICATIONS					
PARAMETER	PARAMETER SYMBOL TEST CONDITIONS VALUES				UNITS
		15 A	T 05 °C	0.46	
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	30 A	- T _J = 25 °C	0.57 V	
Maximum forward voltage drop per leg	V _{FM} (1)	15 A	T. ₁ = 125 °C	0.37	7
		30 A	1J = 125 C	0.50	
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	1.50	mA
iwaximum reverse leakage current per leg	IRM (")	T _J = 125 °C	v _R = nateu v _R	350	IIIA
Maximum junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		1500	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 m	nm from package body	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		- 55 to 150	°C
Maximum thermal resistance, junction to case per leg		В	DC operation	1.5	°C/W
Maximum thermal resistance, junction to case per package		R _{thJC}		0.8	
Approximate weight				2	g
Approximate weight				0.07	oz.
Mounting torque -	minimum			6 (5)	kgf · cm
wounting torque –	maximum			12 (10)	(lbf \cdot in)
Marking device	•		Case style TO-262	30L30	OCT-1



Schottky Rectifier, 2 x 15 A

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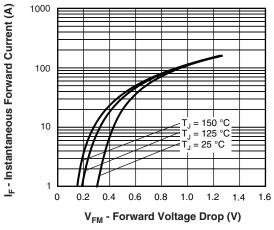


Fig. 1 - Maximum Forward Voltage Drop Characteristics

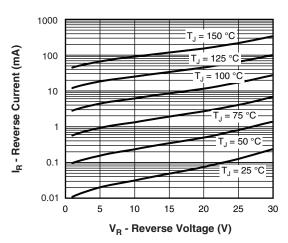


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

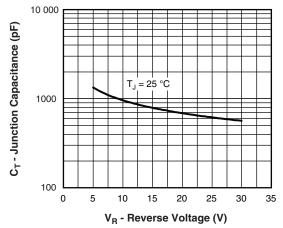


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

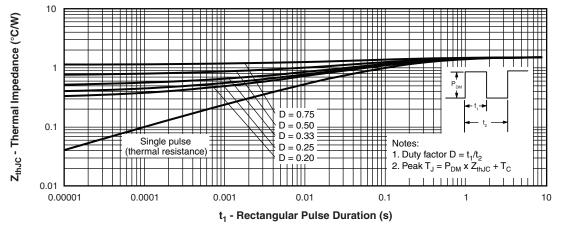


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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Schottky Rectifier, 2 x 15 A



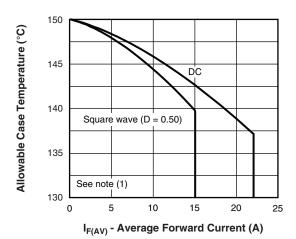


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

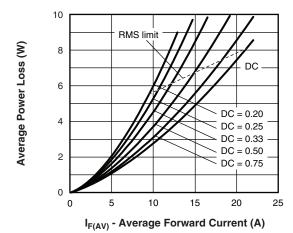


Fig. 6 - Forward Power Loss Characteristics

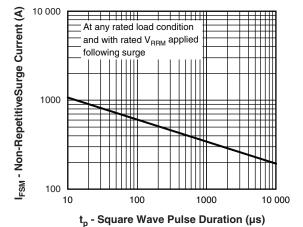


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

 $^{(1)}$ Formula used: $T_C = T_J$ - Pd x $R_{thJC};$ Pd = Forward power loss = $I_{F(AV)}$ x V_{FM} at ($I_{F(AV)}/D$) (see fig. 6)

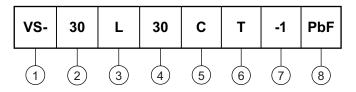


Schottky Rectifier, 2 x 15 A

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Current rating (30 A)

3 - L = Low V_F

4 - Voltage rating (30 = 30 V)

5 - Circuit configuration: C = Common cathode

- T = TO-220

7 - -1 = TO-262

PbF = Lead (Pb)-free

Tube standard pack quantity: 50 pieces

LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95419
Part marking information	www.vishay.com/doc?95420
SPICE model	www.vishay.com/doc?95287

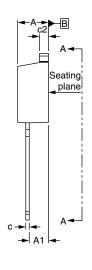


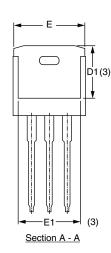
Vishay Semiconductors

TO-262

DIMENSIONS in millimeters and inches

Modified JEDEC outline TO-262 (Datum A)—(2) (3) (3) L1 D D D A (2) (3) L2 B B B B C C C C C C C A A (2)



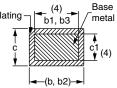


♦0.010**M**|**AM**|**B**|

Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode
3. - Anode



Section B - B and C - C Scale: None

CVMDOL	MILLIM	ETERS	INC	NOTEO	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
Е	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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